



查询TSL1410R供应商

TAOS

TEXAS
ADVANCED
OPTOELECTRONIC
SOLUTIONS™

捷多邦, 专业PCB打样工厂, 24小时加急出货 **TSL1410R**
1280 × 1 LINEAR SENSOR ARRAY WITH HOLD

TAOS043 – AUGUST 2002

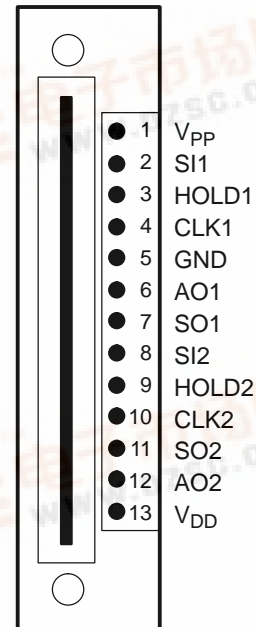
- **1280 × 1 Sensor-Element Organization**
- **400 Dot-Per-Inch (DPI) Sensor Pitch**
- **High Linearity and Uniformity**
- **Wide Dynamic Range . . . 4000:1 (72 dB)**
- **Output Referenced to Ground**
- **Low Image Lag . . . 0.5% Typ**
- **Operation to 8 MHz**
- **Single 3-V to 5-V Supply**
- **Rail-to-Rail Output Swing (AO)**
- **No External Load Resistor Required**
- **Replacement for TSL1410**

Description

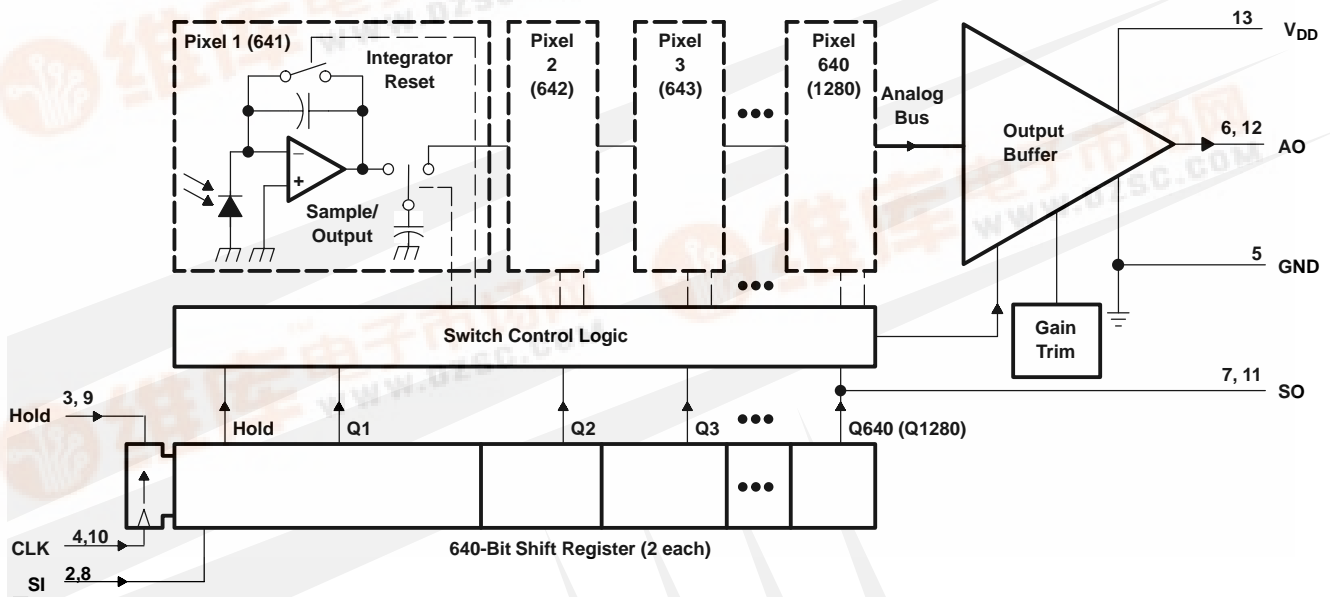
The TSL1410R linear sensor array consists of two sections of 640 photodiodes, each with associated charge amplifier circuitry, aligned to form a contiguous 1280 × 1 pixel array. The device incorporates a pixel data-hold function that provides simultaneous-integration start and stop times for all pixels. The pixels measure 63.5 μm by 55.5 μm with 63.5-μm center-to-center spacing and 8-μm spacing between pixels. Operation is simplified by internal logic that requires only a serial-input (SI) pulse and a clock.

The device is intended for use in a wide variety of applications including mark and code reading, OCR and contact imaging, edge detection and positioning, and optical encoding.

(TOP VIEW)



Functional Block Diagram (each section)



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Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
AO1	6	O	Analog output, section 1.
AO2	12	O	Analog output, section 2.
CLK1	4	I	Clock, section 1. CLK1 controls charge transfer, pixel output, and reset.
CLK2	10	I	Clock, section 2. CLK2 controls charge transfer, pixel output, and reset.
GND	5		Ground (substrate). All voltages are referenced to GND.
HOLD1	3	I	Hold signal. HOLD1 shifts pixel data to parallel buffer. HOLD1 is normally connected to SI1 and HOLD2 in serial mode and to SI1 in parallel mode.
HOLD2	9	I	Hold signal. HOLD2 shifts pixel data to parallel buffer. HOLD2 is normally connected to SI2 in parallel mode.
SI1	2	I	Serial input (section 1). SI1 defines the start of the data-out sequence.
SI2	8	I	Serial input (section 2). SI2 defines the start of the data-out sequence.
SO1	7	O	Serial output (section 1). SO1 provides a signal to drive the SI2 input in serial mode.
SO2	11	O	Serial output (section 2). SO2 provides a signal to drive the SI input of another device for cascading or as an end-of-data indication.
V _{DD}	13		Supply voltage for both analog and digital circuitry.
V _{PP}	1		Normally grounded.

Detailed Description

The sensor consists of 1280 photodiodes, called pixels, arranged in a linear array. Light energy impinging on a pixel generates photocurrent that is then integrated by the active integration circuitry associated with that pixel.

During the integration period, a sampling capacitor connects to the output of the integrator through an analog switch. The amount of charge accumulated at each pixel is directly proportional to the light intensity on that pixel and the integration time.

The output and reset of the integrators are controlled by a 640-bit shift register and reset logic. An output cycle is initiated by clocking in a logic 1 on SI. Another signal, called HOLD, is generated from the rising edge of SI1 when SI1 and HOLD1 are connected together. This causes all 640 sampling capacitors to be disconnected from their respective integrators and starts an integrator reset period. As the SI pulse is clocked through the shift register, the charge stored on the sampling capacitors is sequentially connected to a charge-coupled output amplifier that generates a voltage on analog output AO. The integrator reset period ends 18 clock cycles after the SI pulse is clocked in. Then the next integration period begins. On the 640th clock rising edge, the SI pulse is clocked out on the SO1 pin (section 1) and becomes the SI pulse for section 2 (when SO1 is connected to SI2). The rising edge of the 641st clock cycle terminates the SO1 pulse, and returns the analog output AO of section 1 to high-impedance state. Similarly, SO2 is clocked out on the 1280th clock pulse. Note that a 1281st clock pulse is needed to terminate the SO2 pulse and return AO of Section 2 to the high-impedance state. Sections 1 and 2 may be operated in parallel or in serial fashion.

AO is an op amp-type output that does not require an external pull-down resistor. This design allows a rail-to-rail output voltage swing. With V_{DD} = 5 V, the output is nominally 0 V for no light input, 2 V for normal white level, and 4.8 V for saturation light level. When the device is not in the output phase, AO is in a high-impedance state.

The voltage developed at analog output (AO) is given by:

$$V_{out} = V_{drk} + (R_e)(E_e)(t_{int})$$

where:

V _{out}	is the analog output voltage for white condition
V _{drk}	is the analog output voltage for dark condition
R _e	is the device responsivity for a given wavelength of light given in V/(μJ/cm ²)
E _e	is the incident irradiance in μW/cm ²
t _{int}	is integration time in seconds

A 0.1 μF bypass capacitor should be connected between V_{DD} and ground as close as possible to the device.

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Absolute Maximum Ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{DD}	-0.3 V to 6 V
Input voltage range, V_I	-0.3 V to $V_{DD} + 0.3V$
Input clamp current, I_{IK} ($V_I < 0$) or ($V_I > V_{DD}$)	-20 mA to 20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{DD}$)	-25 mA to 25 mA
Voltage range applied to any output in the high impedance or power-off state, V_O ...	-0.3 V to $V_{DD} + 0.3 V$
Continuous output current, I_O ($V_O = 0$ to V_{DD})	-25 mA to 25 mA
Continuous current through V_{DD} or GND	-40 mA to 40 mA
Analog output current range, I_O	-25 mA to 25 mA
Maximum light exposure at 638 nm	5 mJ/cm ²
Operating free-air temperature range, T_A	0°C to 70°C
Storage temperature range, T_{stg}	-25°C to 85°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “Recommended Operating Conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{DD}	3	5	5.5	V
Input voltage, V_I	0		V_{DD}	V
High-level input voltage, V_{IH}	$V_{DD} \times 0.7$		V_{DD}	V
Low-level input voltage, V_{IL}	0		$V_{DD} \times 0.3$	V
Wavelength of light source, λ	400		1100	nm
Clock frequency, f_{clock}	5		8000	kHz
Sensor integration time, Serial, t_{int}	0.162		100	ms
Sensor integration time, Parallel, t_{int}	0.082		100	ms
Setup time, serial input, $t_{su(SI)}$	20			ns
Hold time, serial input, $t_h(SI)$ (see Note 1)	0			ns
Operating free-air temperature, T_A	0		70	°C
Load capacitance, C_L			330	pF
Load resistance, R_L	300			Ω

NOTE 1: SI must go low before the rising edge of the next clock pulse.



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Electrical Characteristics at $f_{\text{clock}} = 1 \text{ MHz}$, $V_{\text{DD}} = 5 \text{ V}$, $T_A = 25^\circ\text{C}$, $\lambda_p = 640 \text{ nm}$, $t_{\text{int}} = 5 \text{ ms}$, $R_L = 330 \ \Omega$, $E_e = 12.5 \ \mu\text{W}/\text{cm}^2$ (unless otherwise noted) (see Note 2)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{out}	Analog output voltage (white, average over 1280 pixels)	See Note 3	1.6	2	2.4	V
V_{drk}	Analog output voltage (dark, average over 1280 pixels)	$E_e = 0$	0	0.1	0.3	V
PRNU	Pixel response nonuniformity	See Note 4			±20%	
	Nonlinearity of analog output voltage	See Note 5		±0.4%		
	Output noise voltage	See Note 6		1		mVrms
R_e	Responsivity	See Note 7	78	112		V/ ($\mu\text{J}/\text{cm}^2$)
V_{sat}	Analog output saturation voltage	$V_{\text{DD}} = 5 \text{ V}$, $R_L = 330 \ \Omega$	4.5	4.8		V
		$V_{\text{DD}} = 3 \text{ V}$, $R_L = 330 \ \Omega$	2.5	2.8		
SE	Saturation exposure	$V_{\text{DD}} = 5 \text{ V}$, See Note 8		155		nJ/cm ²
		$V_{\text{DD}} = 3 \text{ V}$, See Note 8		90		
DSNU	Dark signal nonuniformity	All pixels, $E_e = 0$, See Note 9		0.05	0.15	V
IL	Image lag	See Note 10		0.5%		
I_{DD}	Supply current	$V_{\text{DD}} = 5 \text{ V}$, $E_e = 0$		30	45	mA
		$V_{\text{DD}} = 3 \text{ V}$, $E_e = 0$		25	40	
I_{IH}	High-level input current	$V_I = V_{\text{DD}}$			10	μA
I_{IL}	Low-level input current	$V_I = 0$			10	μA
C_i	Input capacitance, SI			25		pF
C_i	Input capacitance, CLK			25		pF

- NOTES: 2. All measurements made with a 0.1 μF capacitor connected between V_{DD} and ground.
3. The array is uniformly illuminated with a diffused LED source having a peak wavelength of 640 nm.
4. PRNU is the maximum difference between the voltage from any single pixel and the average output voltage from all pixels of the device under test when the array is uniformly illuminated at the white irradiance level. PRNU includes DSNU.
5. Nonlinearity is defined as the maximum deviation from a best-fit straight line over the dark-to-white irradiance levels, as a percent of analog output voltage (white).
6. RMS noise is the standard deviation of a single-pixel output under constant illumination as observed over a 5-second period.
7. $R_{e(\text{min})} = [V_{\text{out}(\text{min})} - V_{\text{drk}(\text{max})}] \div (E_e \times t_{\text{int}})$
8. $SE(\text{min}) = [V_{\text{sat}(\text{min})} - V_{\text{drk}(\text{min})}] \times (E_e \times t_{\text{int}}) \div [V_{\text{out}(\text{max})} - V_{\text{drk}(\text{min})}]$
9. DSNU is the difference between the maximum and minimum output voltage for all pixels in the absence of illumination.
10. Image lag is a residual signal left in a pixel from a previous exposure. It is defined as a percent of white-level signal remaining after a pixel is exposed to a white condition followed by a dark condition:

$$IL = \frac{V_{\text{out(IL)}} - V_{\text{drk}}}{V_{\text{out(white)}} - V_{\text{drk}}} \times 100$$

Timing Requirements (see Figure 1 and Figure 2)

		MIN	NOM	MAX	UNIT
$t_{\text{su(SI)}}$	Setup time, serial input (see Note 11)	20			ns
$t_{\text{h(SI)}}$	Hold time, serial input (see Note 11 and Note 12)	0			ns
$t_{\text{pd(SO)}}$	Propagation delay time, SO		50		ns
t_w	Pulse duration, clock high or low	50			ns
t_r, t_f	Input transition (rise and fall) time	0		500	ns

- NOTES: 11. Input pulses have the following characteristics: $t_r = 6 \text{ ns}$, $t_f = 6 \text{ ns}$.
12. SI must go low before the rising edge of the next clock pulse.

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Dynamic Characteristics over recommended ranges of supply voltage and operating free-air temperature (see Figures 7 and 8)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_s Analog output settling time to $\pm 1\%$	$R_L = 330 \Omega, C_L = 50 \text{ pF}$		120		ns
$t_{pd(SO)}$ Propagation delay time, SO1, SO2			50		ns

TYPICAL CHARACTERISTICS

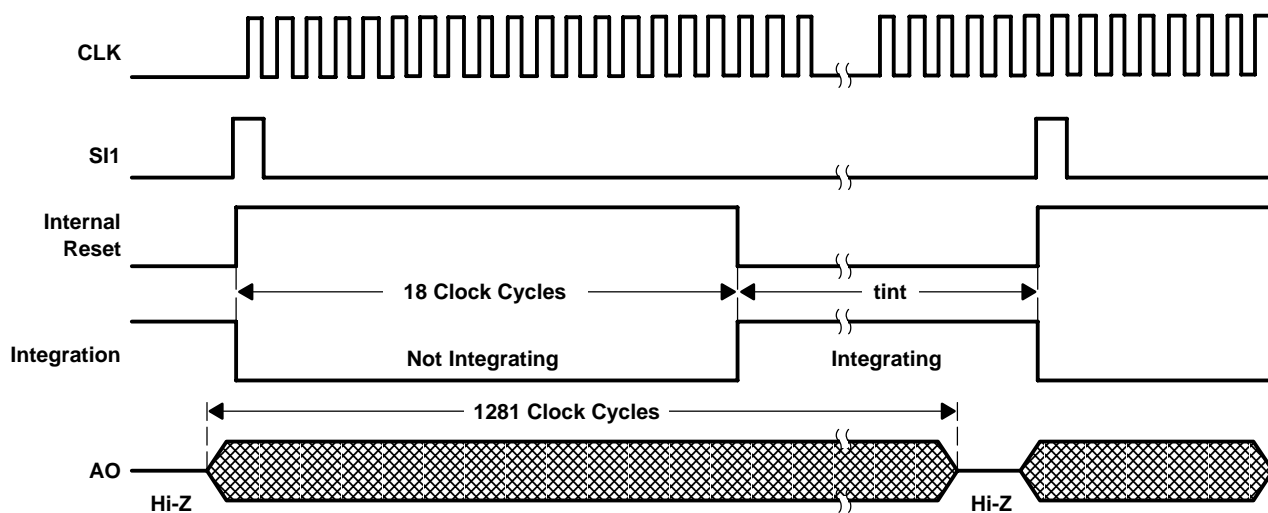


Figure 1. Timing Waveforms (serial connection)

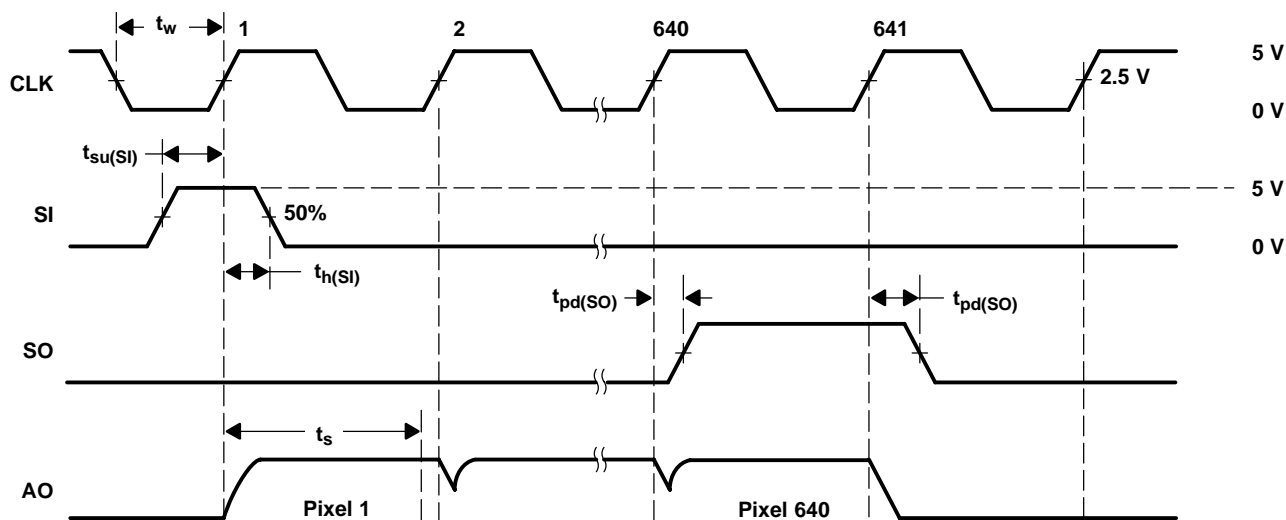


Figure 2. Operational Waveforms (Each Section)

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TYPICAL CHARACTERISTICS

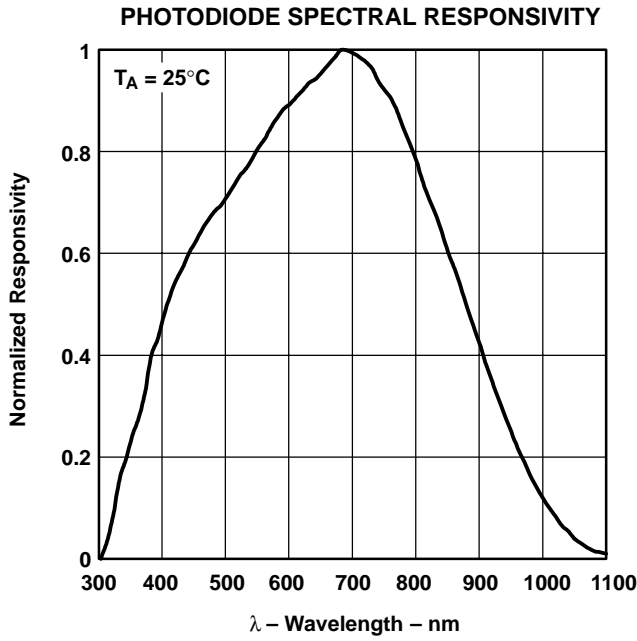


Figure 3

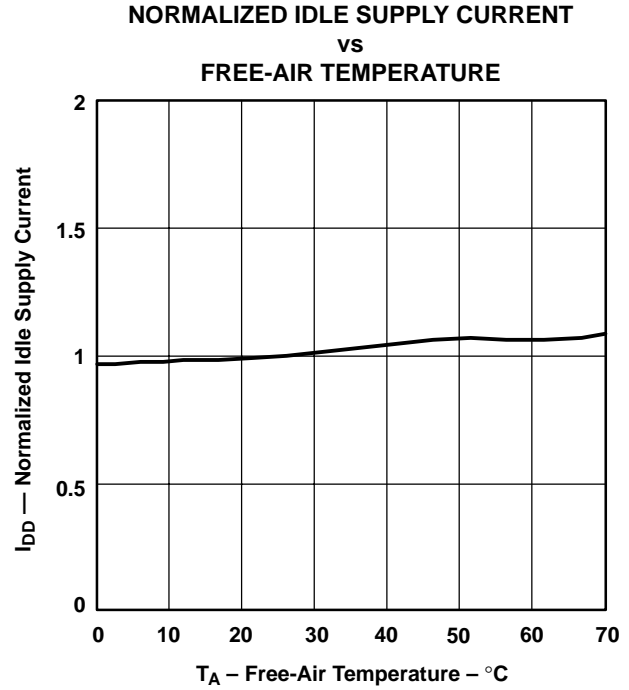


Figure 4

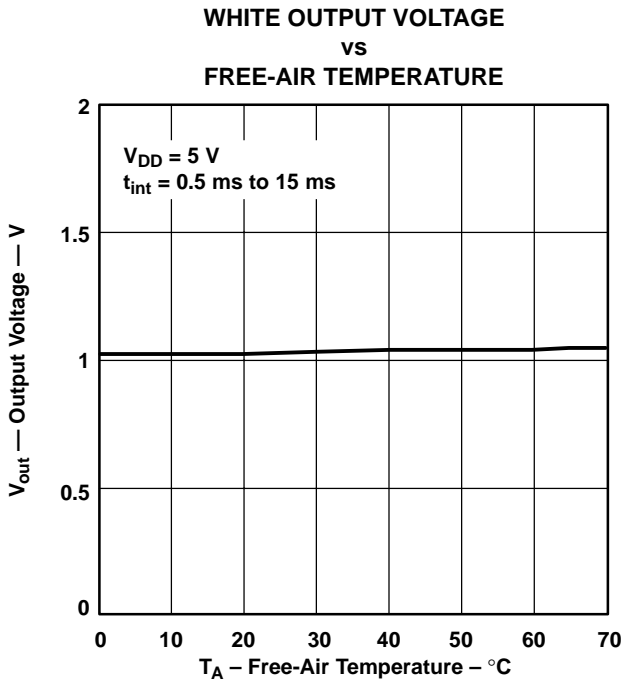


Figure 5

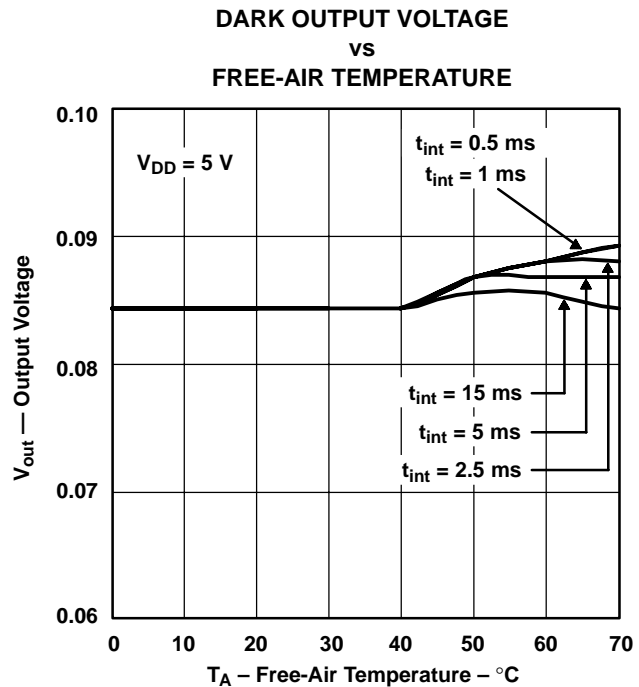


Figure 6

TYPICAL CHARACTERISTICS

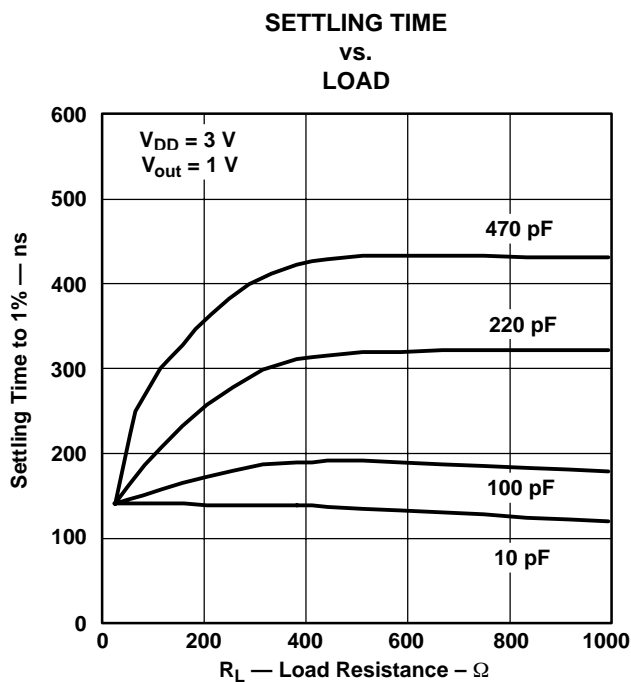


Figure 7

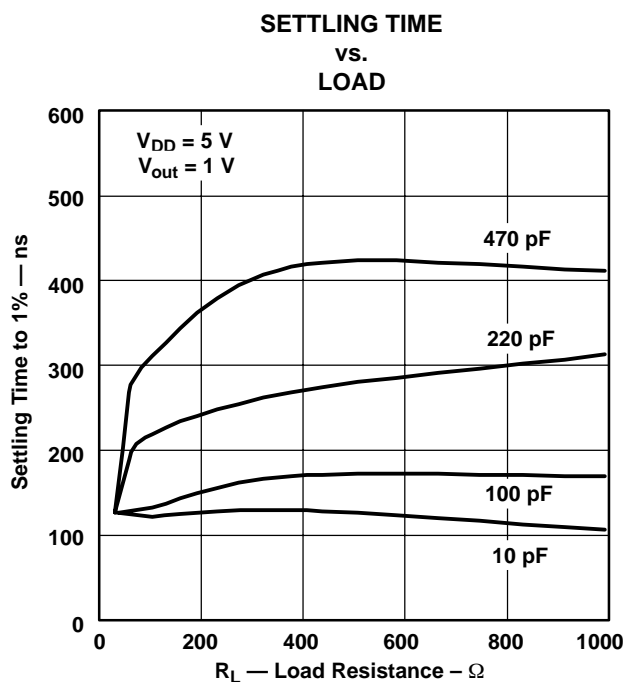


Figure 8

APPLICATION INFORMATION

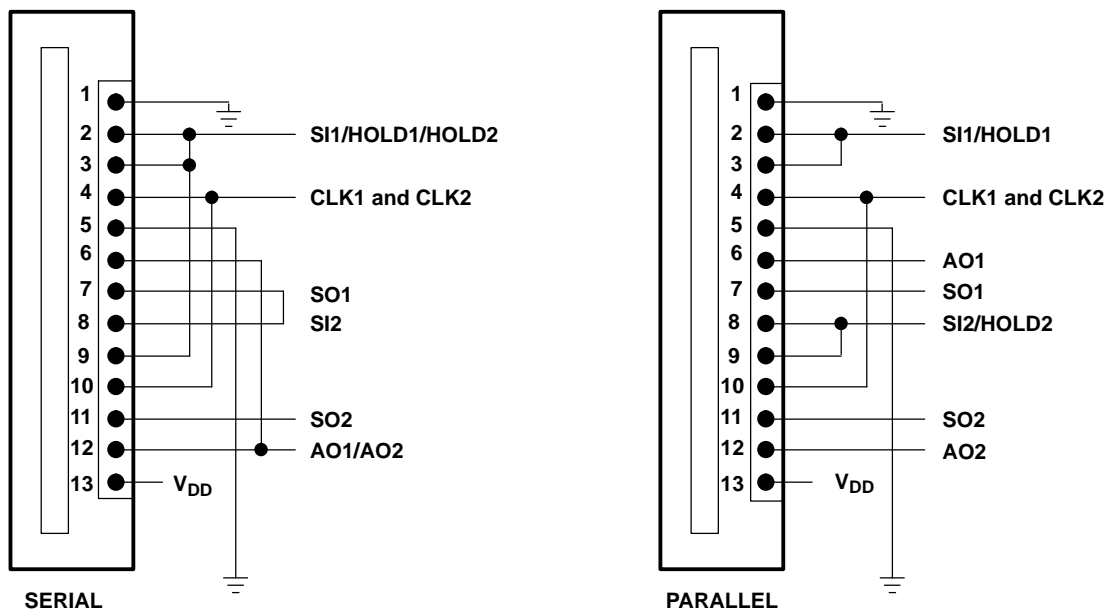
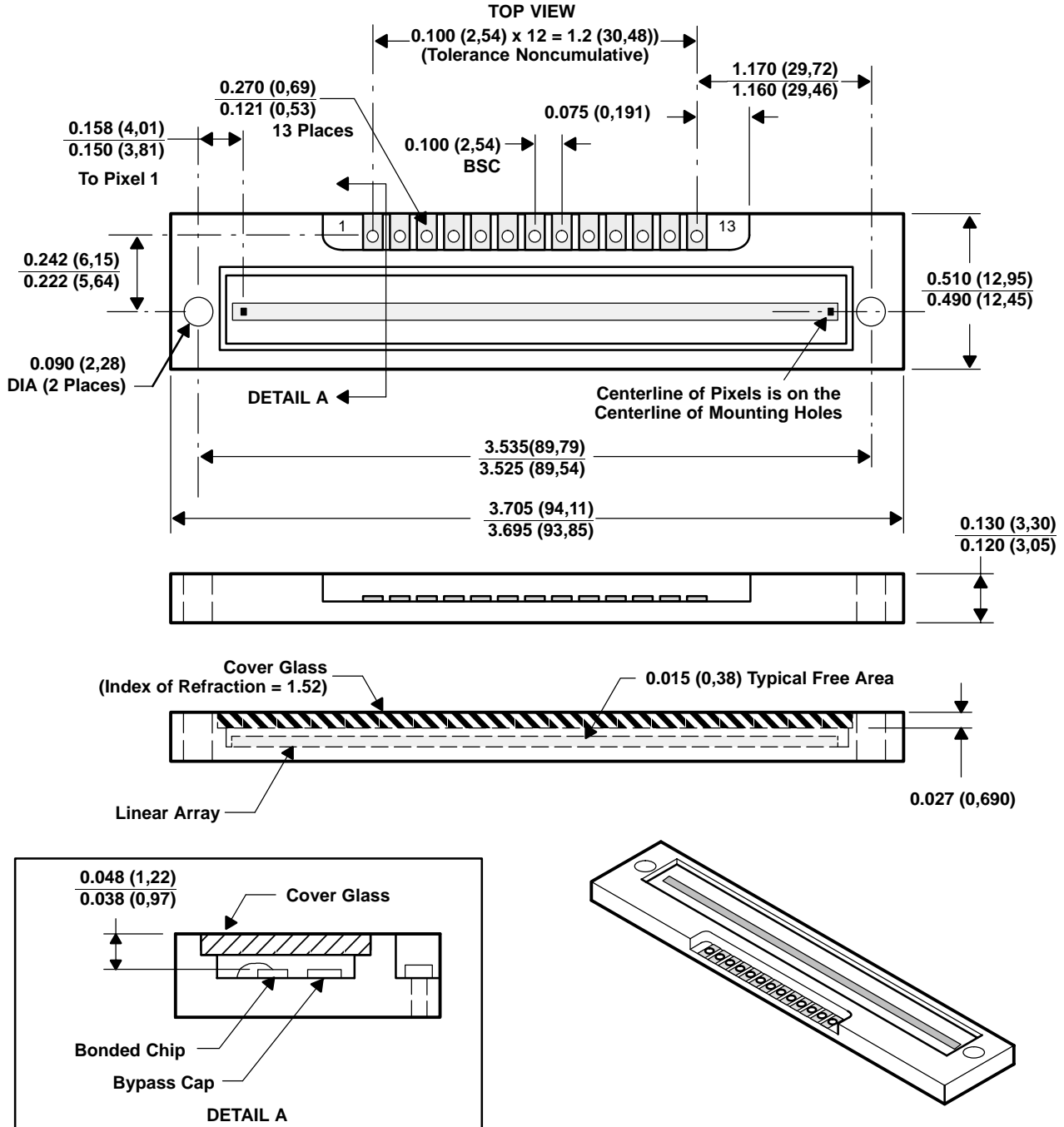


Figure 9. Operational Connections

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MECHANICAL DATA



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Pixel centers are in line with center line of mounting holes.

Figure 10. TSL1410R Mechanical Specifications

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